

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	19	(US-20010002273-\$ or US-20010015430-\$ or US-20020058410-\$ or US-20020094643-\$ or US-20020171146-\$ or US-20020190294-\$ or US-20030134460-\$ or US-20040238876-\$).did. or (US-5182624-\$ or US-5235195-\$ or US-5273910-\$ or US-5341016-\$ or US-5633200-\$ or US-5789312-\$ or US-5923999-\$ or US-6091122-\$ or US-6114736-\$ or US-6284634-\$ or US-6322849-\$).did.	US-PGPUB; USPAT	OR	OFF	2005/02/03 13:28
L2	13	1 and (anneal\$ with ((hydrogen "h.sub.2" "h2") and (nitrogen "n.sub.2" "n2"))))	US-PGPUB; USPAT	OR	OFF	2005/02/03 14:11
L3	2	2 and (wn (tungsten adj nitride))	US-PGPUB; USPAT	OR	OFF	2005/02/03 13:48
L4	19	1 and (anneal\$)	US-PGPUB; USPAT	OR	OFF	2005/02/03 13:46
L5	41	((forming adj gas adj anneal\$) fga) with ((hydrogen "h.sub.2" "h2") and (nitrogen "n.sub.2" "n2"))	US-PGPUB; USPAT	OR	OFF	2005/02/03 13:51
L6	6	5 and (wn (tungsten adj nitride))	US-PGPUB; USPAT	OR	OFF	2005/02/03 13:48
L7	35	5 not 6	US-PGPUB; USPAT	OR	OFF	2005/02/03 13:51
L8	35	7 not (@ad>"20031010" or @rlad>"20031010")	US-PGPUB; USPAT	OR	ON	2005/02/03 14:05
L9	2649	(tungsten adj silicide) with ((cobalt nickel titanium) adj silicide)	US-PGPUB; USPAT	OR	ON	2005/02/03 14:04
L10	467	((tungsten adj silicide) with ((cobalt nickel titanium) adj silicide) with (gate transistor fet mosfet))	US-PGPUB; USPAT	OR	ON	2005/02/03 14:05
L11	438	10 not (@ad>"20031010" or @rlad>"20031010")	US-PGPUB; USPAT	OR	ON	2005/02/03 16:46
L12	396	((gate transistor fet mosfet) with (tungsten w)) and ((gate transistor fet mosfet) with ((tungsten adj nitride) wn)) and ((cobalt titanium nickel) adj (polycide silicide polysilicide))	US-PGPUB; USPAT	OR	OFF	2005/02/03 14:32
L13	33	12 and (anneal\$ with ((hydrogen "h.sub.2" "h2") and (nitrogen "n.sub.2" "n2"))))	US-PGPUB; USPAT	OR	OFF	2005/02/03 14:45

L14	29	13 not (@ad>"20031010" or @rlad>"20031010")	US-PGPUB; USPAT	OR	ON	2005/02/03 14:11
L15	1300	((gate transistor fet mosfet) with (tungsten w)) and ((gate transistor fet mosfet) with ((tungsten adj nitride) wn))	US-PGPUB; USPAT	OR	OFF	2005/02/03 14:32
L16	78	15 and (anneal\$ with ((hydrogen "h.sub.2" "h2") and (nitrogen "n.sub.2" "n2"))))	US-PGPUB; USPAT	OR	OFF	2005/02/03 14:45
L17	73	16 not (@ad>"20031010" or @rlad>"20031010")	US-PGPUB; USPAT	OR	ON	2005/02/03 19:39
L18	44	17 not 14	US-PGPUB; USPAT	OR	ON	2005/02/03 14:46
L19	1	10/051981	US-PGPUB; USPAT	OR	ON	2005/02/03 17:39
L20	0	"10745114"	US-PGPUB; USPAT	OR	ON	2005/02/03 18:26
L21	1	"10/745114"	US-PGPUB; USPAT	OR	ON	2005/02/03 18:26
L22	2	"09/745114"	US-PGPUB; USPAT	OR	ON	2005/02/03 19:38
L23	178	gate with clean with (HF or hydrofluoric)	US-PGPUB; USPAT	OR	ON	2005/02/03 19:40
L24	168	23 not (@ad>"20031010" or @rlad>"20031010")	US-PGPUB; USPAT	OR	ON	2005/02/03 19:41
L25	28	gate with clean with (HF or hydrofluoric) with polysilicon	US-PGPUB; USPAT	OR	ON	2005/02/03 19:40
L26	27	25 not (@ad>"20031010" or @rlad>"20031010")	US-PGPUB; USPAT	OR	ON	2005/02/03 19:41
S1	38	(HO-TZU-EN CHANG-CHIH-HAO WU-CHANG-RONG SU-KUO-HUI). in.	US-PGPUB; USPAT	OR	OFF	2005/02/02 21:06
S2	372	nanya.asn.	US-PGPUB; USPAT	OR	OFF	2005/02/02 19:03
S3	26	S2 and (stack\$ with (gate transistor fet mosfet))	US-PGPUB; USPAT	OR	OFF	2005/02/02 21:07
S4	151	(stack\$ with (gate transistor fet mosfet)) and ((gate transistor fet mosfet) with (tungsten w)) and ((gate transistor fet mosfet) with ((tungsten adj nitride) wn)) and ((cobalt titanium nickel) adj (polycide silicide polysilicide))	US-PGPUB; USPAT	OR	OFF	2005/02/03 14:10
S5	15	S4 and (anneal\$ with (wn (tungsten adj nitride)))	US-PGPUB; USPAT	OR	OFF	2005/02/02 18:28

S6	155	(stack\$ with (gate transistor fet mosfet)) and ((gate transistor fet mosfet) with (tungsten w)) and ((gate transistor fet mosfet) with ((tungsten adj nitride) wn)) and ((cobalt titanium nickel) adj (polycide silicide polysilicide) or cosi tisi nisi)	US-PGPUB; USPAT	OR	OFF	2005/02/02 18:27
S7	16	S6 and (anneal\$ with (wn (tungsten adj nitride)))	US-PGPUB; USPAT	OR	OFF	2005/02/03 13:29
S8	1	S7 not S5	US-PGPUB; USPAT	OR	OFF	2005/02/02 18:27
S9	23	S4 and (anneal\$ with ((hydrogen "h.sub.2") and (nitrogen "n.sub.2"))))	US-PGPUB; USPAT	OR	OFF	2005/02/03 13:28
S10	22	S9 not S7	US-PGPUB; USPAT	OR	OFF	2005/02/02 18:29
S11	94	(anneal\$ with ((hydrogen "h.sub.2") and (nitrogen "n.sub.2")))) with (gate transistor)	US-PGPUB; USPAT	OR	ON	2005/02/02 21:10
S12	84	S11 not (@ad>"20031010" or @rlad>"20031010")	US-PGPUB; USPAT	OR	ON	2005/02/03 13:51
S13	2	(w tungsten) with ((tungsten adj nitride) wn) with (anneal\$ with (hydrogen "h.sub.2") with (nitrogen "n.sub.2"))	US-PGPUB; USPAT	OR	OFF	2005/02/02 21:07
S14	2	S13 not (@ad>"20031010" or @rlad>"20031010")	US-PGPUB; USPAT	OR	ON	2005/02/02 19:10
S15	1	S2 and (anneal\$ with (hydrogen "h.sub.2") with (nitrogen "n.sub.2"))	US-PGPUB; USPAT	OR	OFF	2005/02/02 21:09
S16	1	S2 and (anneal\$ with (hydrogen "h.sub.2") with (nitrogen "n.sub.2"))	US-PGPUB; USPAT	OR	ON	2005/02/02 21:09
S17	1	S2 and (anneal\$ with ((hydrogen "h.sub.2") and (nitrogen "n.sub.2"))))	US-PGPUB; USPAT	OR	ON	2005/02/02 21:09
S18	98	(anneal\$ with ((hydrogen "h.sub.2") and (nitrogen "n.sub.2")))) with (gate transistor fet mosfet nfet pfet pmosfet nmosfet nmos pmos)	US-PGPUB; USPAT	OR	ON	2005/02/02 21:11
S19	4	S18 not S11	US-PGPUB; USPAT	OR	ON	2005/02/02 21:11
S20	4	S19 not (@ad>"20031010" or @rlad>"20031010")	US-PGPUB; USPAT	OR	ON	2005/02/02 21:11